

N-channel TrenchMOS standard level FET 11 September 2012

Product data sheet

Product profile 1.

1.1 General description

Standard level N-channel MOSFET in a SOT226 package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

1.2 Features and benefits

- AEC Q101 compliant •
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with VGS(th) rating of greater than 1V at 175 °C

1.3 Applications

- 12V, 24V and 48V Automotive systems
- Electric and electro-hydraulic power steering •
- Motors, lamps and solenoid control •
- Start-Stop micro-hybrid applications
- Transmission control •
- Ultra high performance power switching •

1.4 Quick reference data

Table 1. C							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	100	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	[1]	-	-	120	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	349	W
Static chara	acteristics	·					
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11		-	4.1	5.2	mΩ
Dynamic ch	naracteristics			1			
Q _{GD}	gate-drain charge	V_{GS} = 10 V; I _D = 25 A; V _{DS} = 80 V; T _j = 25 °C; Fig. 13; Fig. 14		-	65	-	nC

Quick reference data Table 1

[1] Continuous current is limited by package.

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2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	D	drain		
3	S	source		G C C
mb	D	mounting base; connected to drain	1 2 3 I2PAK (SOT226)	mbb076 S

3. Ordering information

Table 3. Ordering information						
Type number Package						
	Name	Description	Version			
BUK7E5R2-100E	I2PAK	plastic single-ended package (I2PAK); TO-262	SOT226			

4. Marking

Table 4. Marking codes	
Type number	Marking code
BUK7E5R2-100E	BUK7E5R2-100E

5. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	100	V
V _{DGR}	drain-gate voltage	R _{GS} = 20 kΩ		-	100	V
V _{GS}	gate-source voltage	T _j ≤ 175 °C; DC		-20	20	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	120	А
		T _{mb} = 100 °C; V _{GS} = 10 V; <u>Fig. 1</u>		-	112	А
I _{DM}	peak drain current	T_{mb} = 25 °C; pulsed; $t_p \le 10 \ \mu$ s; Fig. 4		-	631	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	349	W
T _{stg}	storage temperature			-55	175	°C

BUK7E5R2-100E

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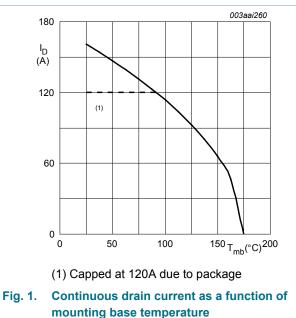
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Symbol	Parameter	Conditions		Min	Мах	Unit
Tj	junction temperature			-55	175	°C
Source-dra	in diode					
I _S	source current	T _{mb} = 25 °C	[1]	-	120	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^\circ C$		-	631	А
Avalanche	ruggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$\label{eq:ID} \begin{array}{l} I_{D} = 120 \; A; \; V_{sup} \leq 100 \; V; \; R_{GS} = 50 \; \Omega; \\ V_{GS} = 10 \; V; \; T_{j(init)} = 25 \; ^{\circ}C; \; unclamped; \\ \hline Fig. \; 3 \end{array}$	[2][3]	-	387	mJ

[1] Continuous current is limited by package.

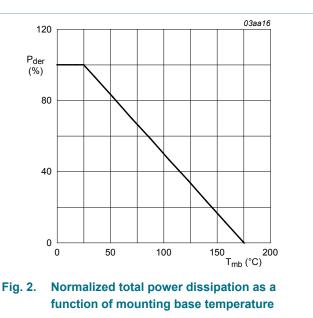
[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.



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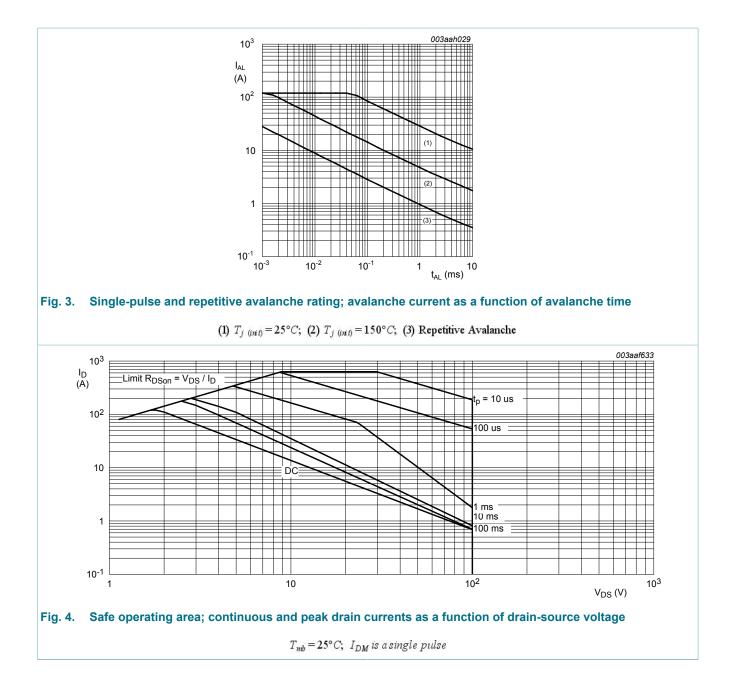
 $V_{GS} \ge 10 V$



$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

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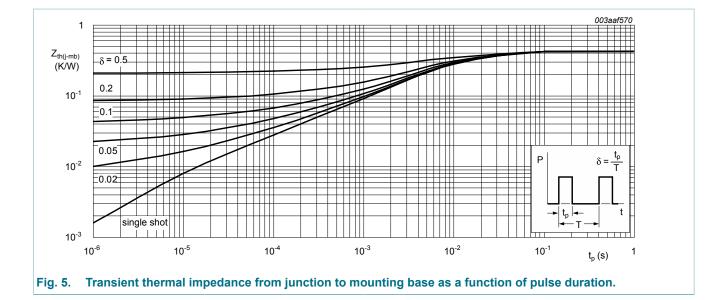


6. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	-	0.43	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	vertical in still air		-	65	-	K/W

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Characteristics 7.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · ·				
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	100	-	-	V
	breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	90	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ Fig. 9; Fig. 10	2.4	3	4	V
	ID = 1 mA; VDS = VGS; Tj = -55 °C; - - 4.5 ID = 1 mA; VDS = VGS; Tj = -55 °C; - - - 4.5 ID = 1 mA; VDS = VGS; Tj = 175 °C; I - </td <td>V</td>	V				
V _{GS(th)}	-	,	1	-	-	V
I _{DSS}	drain leakage current	V_{DS} = 100 V; V_{GS} = 0 V; T_j = 25 °C	-	0.15	2	μA
		V_{DS} = 100 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11	-	4.1	5.2	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 11; Fig. 12	-	-	14	mΩ
Dynamic ch	naracteristics	· · ·				
Q _{G(tot)}	total gate charge	I_D = 25 A; V_{DS} = 80 V; V_{GS} = 10 V;	-	180	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 13; Fig. 14</u>	-	34	-	nC
Q _{GD}	gate-drain charge		-	65	-	nC

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 25 V; f = 1 MHz;	-	8860	11810	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 15</u>	-	770	925	pF
C _{rss}	reverse transfer capacitance		-	546	750	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 80 \text{ V}; \text{ R}_{L} = 3.2 \Omega; \text{ V}_{GS} = 10 \text{ V};$ $R_{G(ext)} = 5 \Omega$	-	37	-	ns
t _r	rise time		-	62	-	ns
t _{d(off)}	turn-off delay time		-	158	-	ns
t _f	fall time		-	80	-	ns
L _D internal drain inductance		from upper edge of drain mounting base to centre of die	-	2.5	-	nH
		from drain lead 6mm from package to centre of die	-	4.5	-	nH
L _S	internal source inductance	measured from source lead to source bond pad	-	7.5	-	nH
Source-dra	in diode	· · · ·				
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 16</u>	-	0.77	1.2	V
t _{rr}	reverse recovery time	I_{S} = 20 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V;	-	65	-	ns
Qr	recovered charge	V _{DS} = 25 V	-	191	-	nC

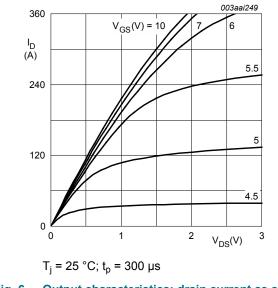
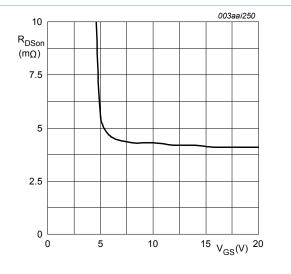


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

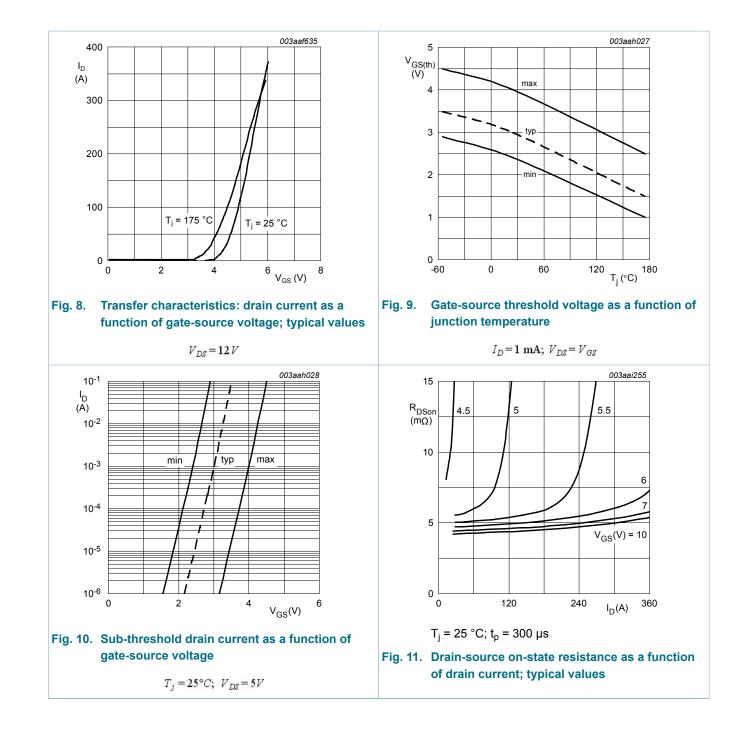




 $T_j = 25^{\circ}C; I_D = 25A$

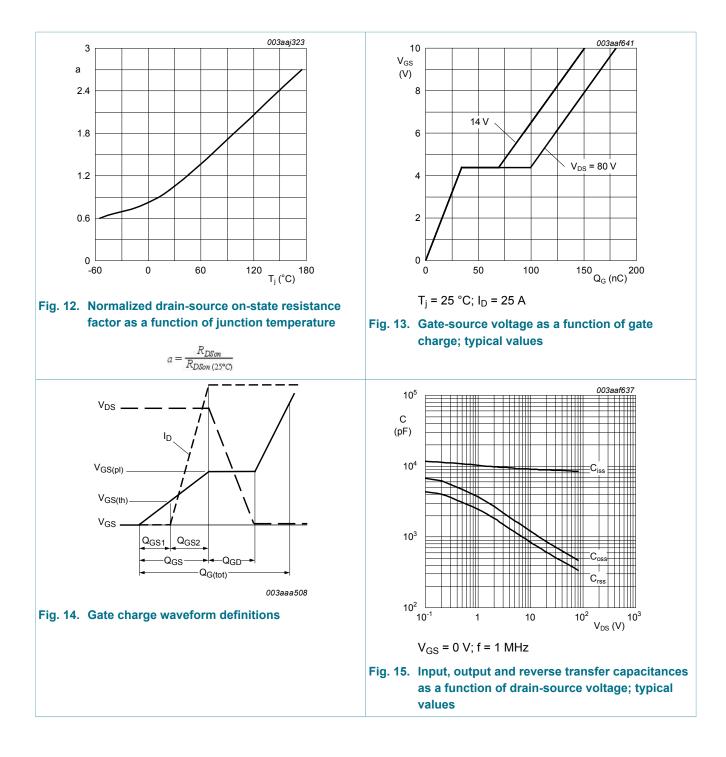
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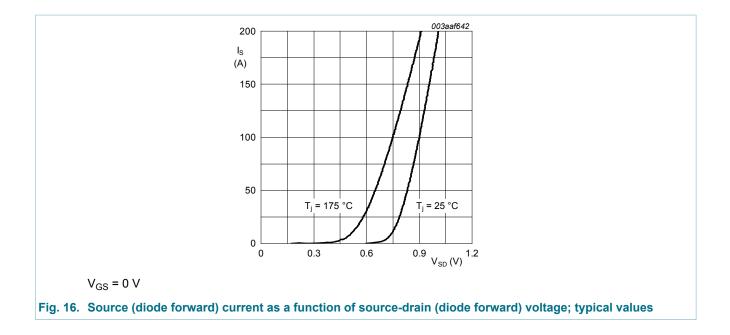
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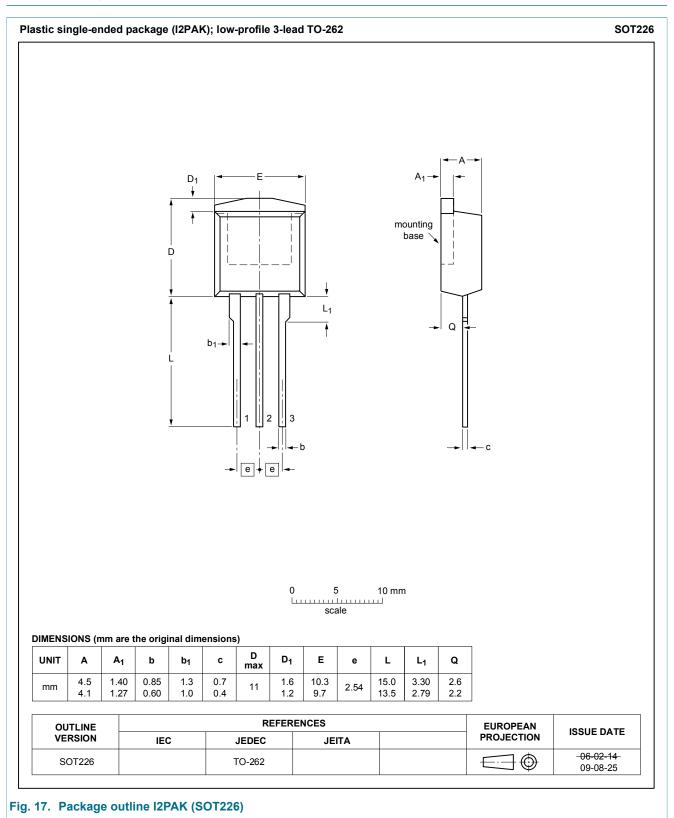
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8. Package outline



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9. Legal information

9.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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